

Operational Amplifiers**CA3401****Quad Single-Supply Operational Amplifier**

For Automotive Electronics and Industrial Control Systems

**Features:**

- Single-supply operation - +5 V to +18 Vdc
- Internally compensated
- Wide unity-gain bandwidth - 5 MHz typ.
- Low input bias current - 50 nA typ.
- High open-loop gain - 2000 V/V typ.

The RCA-3401 is a high-gain monolithic quad operational amplifier designed specifically for applications using a single positive power supply. No external compensation is necessary. Closed-loop stability in each of the four independent amplifiers is maintained by a 3-pF on-chip capacitor. The CA3401 is ideally suited for applications in industrial control systems, automotive electronics, and general purpose amplifiers, e.g. oscillators, tachometers, active filters, and multichannel amplifiers.

The CA3401 is supplied in a 14-lead dual-in-line plastic package (E suffix), and is also available in chip form (H suffix). It is a direct replacement for the Motorola MC3401P, and is pin-compatible with the Motorola MC3301P and the National Semiconductor LM3900N. The CA3401 can be operated over the temperature range of -55 to +125°C, although the limit values of certain specified electrical characteristics apply only over the range of 0 to +75°C.

**Applications:**

- Automotive
- Constant-Current Sources
- Multivibrators
- Sample and Hold
- Square-Wave Generator
- Oscillators
- Tachometers
- Active Filters
- Multi-Channel Amplifiers
- Summing Amplifiers

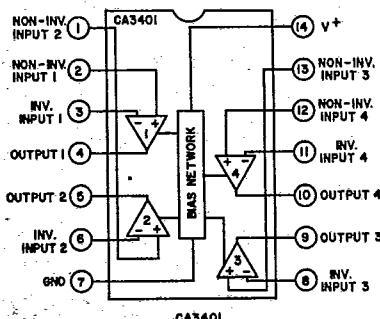


Fig. 1 - Block diagram of CA3401.

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**MAXIMUM RATINGS, Absolute-Maximum Values at TA = 25°C**

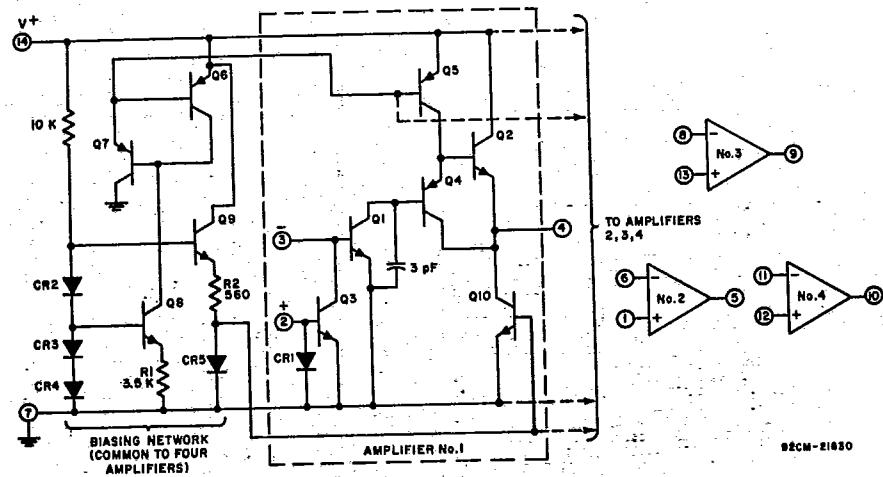
DC SUPPLY VOLTAGE .....	+18 V
INPUT SIGNAL CURRENT .....	5 mA
DEVICE DISSIPATION:	
Up to TA = 25°C .....	625 mW
Above TA = 25°C .....	Derate linearly 5 mW/°C
AMBIENT TEMPERATURE RANGE:	
Operating .....	-55 to + 125°C
Storage .....	-65 to + 150°C
LEAD TEMPERATURE (During soldering):	
At distance 1/16 ± 1/32 inch (1.68 ± 0.78 mm) from case for 10 seconds max. ....	300°C

File Number 630

## CA3401

ELECTRICAL CHARACTERISTICS AT  $T_A = 25^\circ\text{C}$ ,  $V^+ = 15 \text{ V}$  (Unless Indicated Otherwise)

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
<b>STATIC</b>					
Output Voltage: High, $V_{OH}$		13.5	14.2	—	V
Low, $V_{OL}$		—	0.03	0.1	
Max. Undistorted Output Swing, $V_{OP-P}$	$0^\circ\text{C} \leq T_A \leq 75^\circ\text{C}$	10	13.5	—	
Output Current: Source, $I_{SOURCE}$		5	10	—	mA
Sink, $I_{SINK}$		0.5	1	—	
Total Quiescent Current: $I_Q$		—	6.9	10	mA
Noninverting inputs open		—	7.8	14	
Noninverting inputs grounded					
Input Bias Current, $I_{IB}$	$R_L = \infty, T_A = 25^\circ\text{C}$	—	50	300	nA
	$R_L = \infty, 0^\circ\text{C} \leq T_A \leq 75^\circ\text{C}$	—	—	500	
<b>DYNAMIC</b>					
Open-Loop Voltage Gain, AOL	$T_A = 25^\circ\text{C}$	1000	2000	—	V/V
	$0^\circ\text{C} \leq T_A \leq 75^\circ\text{C}$	800	—	—	
Input Resistance, $R_I$		0.1	1	—	MΩ
Slew Rate, SR	$C_L = 100 \text{ pF}, R_L = 5 \text{ k}\Omega$	—	0.6	—	V/μs
Unity Gain Bandwidth, BW		—	5	—	MHz
Phase Margin, φ		—	70	—	Degrees
Power Supply Rejection	$f = 100 \text{ Hz}$	—	55	—	dB
Channel Separation, $e_01/e_02$	$f = 1 \text{ kHz}$	—	65	—	dB



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## TEST CIRCUITS

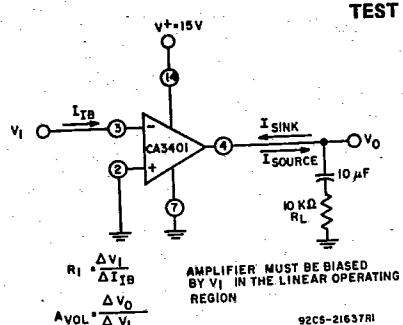


Fig.3 – Open-loop gain and input resistance, input bias current and output current test circuit.

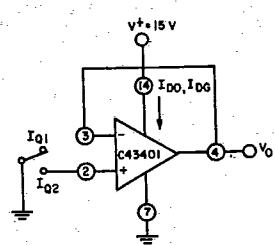


Fig.4 – Quiescent power supply current test circuit.

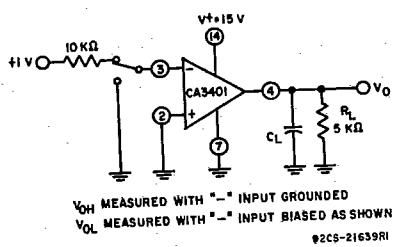


Fig.5 – Output voltage swing test circuit.

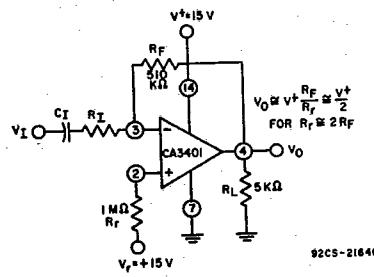


Fig.6 – Peak-to-peak output voltage test circuit.

## TYPICAL CHARACTERISTIC CURVES

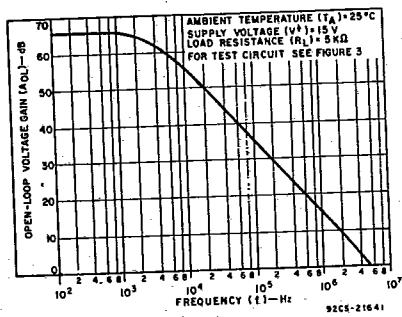


Fig.7 – Open-loop voltage gain vs. frequency.

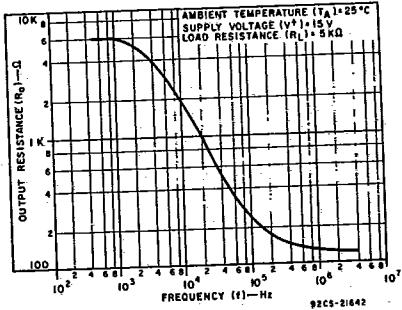


Fig.8 – Output resistance vs. frequency.

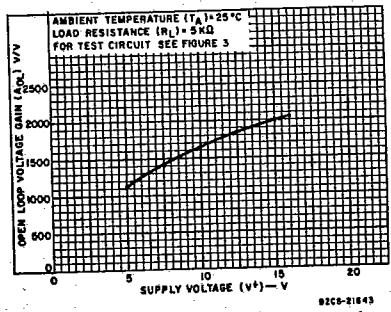


Fig.9 – Open-loop voltage gain vs. supply voltage.

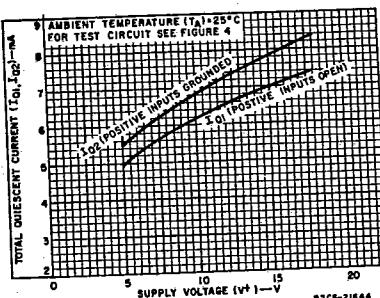


Fig.10 – Supply current vs. supply voltage.

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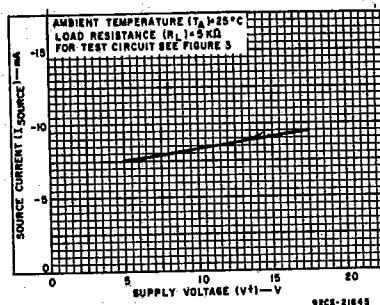


Fig.11 — Source current vs. supply voltage.

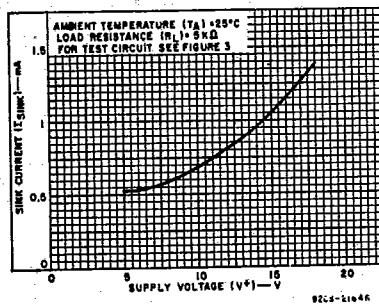
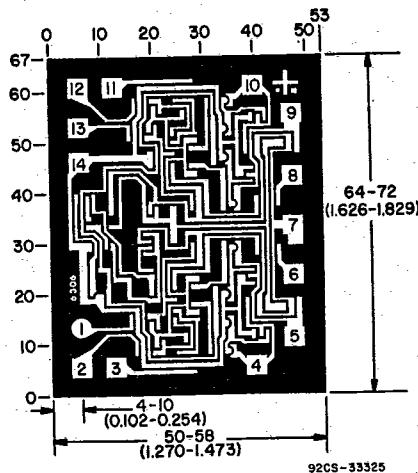


Fig.12 — Sink current vs. supply voltage.



Dimensions and pad layout for CA3401H

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils ( $10^{-3}$  inch).

The photographs and dimensions represent a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.